

DESCRIPTION

The 1SS181 is available in SOT-23 package.

FEATURES

● Low forward voltage : V_{F (3)} = 0.92V (typ.)

• Fast reverse recovery time : t_{RR} = 1.6ns (typ.)

Small total capacitance : C_T = 2.2pF (typ.)

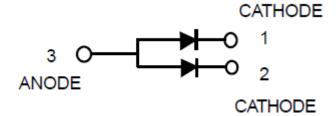
RoHS Compliant

Available in SOT-23 package

ORDERING INFORMATION

Package Type	Part Number				
SOT-23	1SS181				
Note	Note 3,000Tape/Reel				
AiT provides all RoHS Compliant Products					

PIN DESCRIPTION



ABSOLUTE MAXIMUM RATINGS

 $T_A = 25^{\circ}C$

V _{RM} , Maximum (peak) reverse voltage	85 V
V _R , Reverse voltage	80 V
I _{FM} , Maximum (peak) forward current	300mA ^{Note1}
Io, Average forward current	100mA Note1
I _{FSM} , Surge current (10ms)	2A Note1
P _D , Power dissipation	150mW
T _J , Junction temperature	125 °C
T _{STG} , Storage temperature range	-55 °C ~+125 °C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

NOTE1: Unit rating. Total rating = Unit rating × 1.5

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ELECTRICAL CHARACTERISTICS

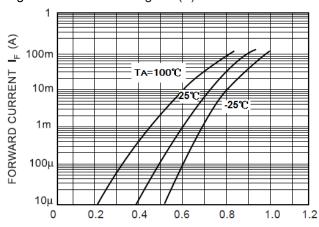
 $T_A = 25^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур.	Max	Unit
Forward voltage	V _{F (1)}	I _F = 1mA	-	0.61	ı	V
	V _{F (2)}	I _F = 10mA	-	0.74	1	
	V _{F (3)}	I _F = 100mA	-	0.90	1.20	
Reverse current	I _{R (1)}	V _R = 30V	-	-	0.1	μΑ
	I _{R (2)}	V _R = 80V	-	-	0.5	
Total capacitance	Ст	V _R = 0, f = 1MHz	-	2.2	4.0	pF
Reverse recovery time	t _{RR}	I _F = 10mA (Figure 5)	-	1.6	4.0	ns

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TYPICAL CHARACTERISTICS

Figure 1. Forward Voltage $V_F(V)$



10 μ

TA=100°C

Y

1μ

75°C

25°C

100n

25°C

40

60

80

Figure 3. Reverse Voltage V_R(V)

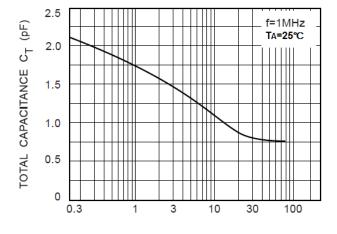


Figure 4. Forward Current I_F(mA)

20

1n

0

Figure 2. Reverse Voltage V_R(V)

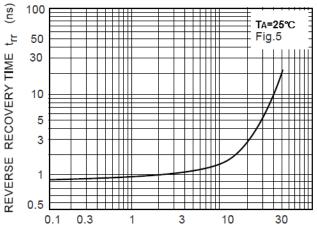
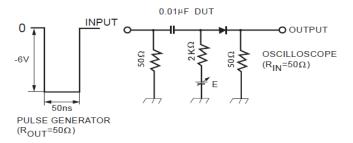
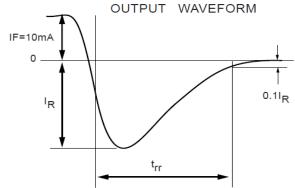


Figure 5. Reverse recovery time (t_{RR}) test circuit

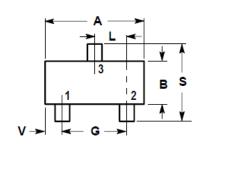


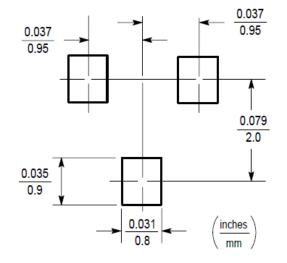


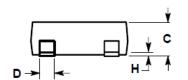
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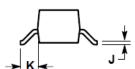
PACKAGE INFORMATION

Dimension in SOT-23 Package (Unit: mm)









DIM	MILLIN	METERS	INCHES		
	MIN	MAX	MIN	MAX	
А	2.80	3.04	0.1102	0.1197	
В	1.20	1.40	0.0472	0.0551	
С	0.89	1.11	0.0350	0.0440	
D	0.37	0.50	0.0150	0.0200	
G	1.78	2.04	0.0701	0.0807	
Н	0.013	0.100	0.0005	0.0040	
J	0.085	0.177	0.0034	0.0070	
K	0.35	0.69	0.0140	0.0285	
L	0.89	1.02	0.0350	0.0401	
S	2.10	2.64	0.0830	0.1039	
V	0.45	0.60	0.0177	0.0236	

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